

HAC RF TESTREPORT

No. I18Z60272-SEM03

For

TCL Communication Ltd.

GSM Quad-band/HSPA-UMTS Six-band/LTE 18-bands mobile phone

Model Name: BBE100-2

With

Hardware Version: 04

Software Version: V6R13-6

FCC ID: 2ACCJN024

Results Summary: M Category = M4

Issued Date: 2018-7-2



Note:

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REPORT HISTORY

Report Number	Revision Issue Date		Description	
I18Z60272-SEM03	Rev.0	2018-7-2	Initial creation of test report	



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1 Test Laboratory

1.1 Testing Location

CompanyName:	CTTL(Shouxiang)
Address:	No. 51 Shouxiang Science Building, Xueyuan Road, Haidian District,
	Beijing, P. R. China100191

1.2 Testing Environment

Temperature:	18°C~25°C,
Relative humidity:	30%~ 70%
Ground system resistance:	< 0.5 Ω

Ambient noise is checked and found very low and in compliance with requirement of standards. Reflection of surrounding objects is minimized and in compliance with requirement of standards.

1.3 Project Data

Project Leader:	Qi Dianyuan
Test Engineer:	Lin Hao
Testing Start Date:	2018-6-25
Testing End Date:	2018-6-26

1.4 Signature

Lin Xiaojun

(Prepared this test report)

Qi Dianyuan

(Reviewed this test report)

Lu Bingsong

Deputy Director of the laboratory

(Approved this test report)



2 Client Information

2.1 Applicant Information

Company Name:	ame: TCL Communication Ltd.	
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	Shenzhen, Guangdong	
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2.2 Manufacturer Information

Company Name:	TCL Communication Ltd.	
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	Shenzhen, Guangdong	
City:	Shenzhen	
Country: China		
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Fax: 0086-75536612000-81722		



3 Equipment Under Test (EUT) and Ancillary Equipment (AE)

3.1 About EUT

Description:	GSM Quad-band/HSPA-UMTS Six-band/LTE 18-bands mobile phone		
Model name:	BBE100-2		
Operating mode(s):	GSM 850/900/1800/1900 WCDMA850/900/1700/1900/2100		
Operating mode(s):	LTE B1/2/3/4/5/7/8/12/13/17/20/28/29/38/39/40/41/66, BT, WLAN		

3.2 Internal Identification of EUT used during the test

EUT ID*	IMEI	HW Version	SW Version
EUT1	015138000010588	04	V6R13-6
EUT2	015138000009671	04	V6R13-6
EUT3	015138000200049	04	V6R13-6

^{*}EUT ID: is used to identify the test sample in the lab internally.

3.3 Internal Identification of AE used during the test

AE ID*	Description	Model	SN	Manufacturer
AE1	Battery	TLp029C1	/	BYD

^{*}AE ID: is used to identify the test sample in the lab internally.

3.4 Air Interfaces / Bands Indicating Operating Modes

Air-interface	Band(MHz)	Туре	C63.19/tested	Simultaneous Transmissions	ОТТ
GSM	850	VO	Yes		NA
OOW	1900	VO		BT, WLAN	
GPRS/EDGE	850	DT	NA	DI, WLAIN	
GFR3/LDGL	1900	וט	INA		
	850		O Yes	BT, WLAN	NA
WCDMA	1700	VO			
(UMTS)	1900				
	HSPA	DT	NA		
LTE	Band 2/5/7/12/13/41/66	V/D	Yes	BT, WLAN	NA
ВТ	2450	DT	NA	GSM, WCDMA, LTE	NA
WLAN	2450	V/D	Yes	GSM, WCDMA, LTE	NA
WLAN	5G	V/D	Yes	GSM, WCDMA, LTE	NA

VO: Voice CMRS/PSTN Service Only V/D: Voice CMRS/PSTN and Data Service DT: Digital Transport

^{*} HAC Rating was not based on concurrent voice and data modes, Non current mode was found to represent worst case rating for both M and T rating



4 CONDUCTED OUTPUT POWER MEASUREMENT

4.1 Summary

During the process of testing, the EUT was controlled via Agilent Digital Radio Communication tester (E5515C) to ensure the maximum power transmission and proper modulation. This result contains conducted output power for the EUT. In all cases, the measured output power should be greater and within 5% than EMI measurement.

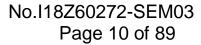
4.2 Conducted Power

CCM		Conducted Power (dBm)			
GSM 850MHz	Channel 251(848.8MHz)	Channel 190(836.6MHz)	Channel 128(824.2MHz)		
OSUMITIZ	32.38	32.41	32.28		
GSM		Conducted Power(dBm)			
1900MHz	Channel 810(1909.8MHz)	Channel 661(1880MHz)	Channel 512(1850.2MHz)		
1900141112	29.26	29.08	28.96		
WCDMA		Conducted Power (dBm)			
850MHz	Channel 4233(846.6MHz)	Channel 4182(836.4MHz)	Channel 4132(826.4MHz)		
OJUNI12	23.44	23.48	23.52		
MCDMA		Conducted Power (dBm)			
WCDMA	Channel 1513 (1752.6MHz)	Channel 1412 (1732.4MHz)	Channel 1312 (1712.4MHz)		
1700MHz	23.72	23.85	23.86		
WCDMA		Conducted Power (dBm)			
1900MHz	Channel 9538(1907.6MHz)	Channel 9400(1880MHz)	Channel 9262(1852.4MHz)		
190011112	23.75	23.70	23.74		
LTE		Conducted Power (dBm)			
Band2	Channel 19100(1900MHz)	Channel18900(1880MHz)	Channel 18700(1860MHz)		
QPSK	23.45	23.40	23.37		
LTE		Conducted Power (dBm)			
Band5	Channel 20600(844MHz)	Channel 20525(836.5MHz)	Channel20450(829MHz)		
QPSK	23.08	23.13	23.15		
LTE		Conducted Power (dBm)	_		
Band7	Channel 21350(2560MHz)	Channel21100(2535MHz)	Channel 20850(2510MHz)		
QPSK	23.41	23.53	23.42		
LTE		Conducted Power (dBm)			
Band12	Channel 23130(711MHz)	Channel 23095(707.5MHz)	Channel23060(704MHz)		
QPSK	23.12	23.07	23.10		
LTE	Conducted Power (dBm)				
Band13	Channel 23230(782MHz)				
QPSK	23.02				
LTE	Conducted Power (dBm)				



Band41	Channel	Chann	el	Channel	С	hannel	Channel
QPSK	41490(2680MH	41055(263	6.5M	40620(2593MH	4018	5(2549.5M	39750(2506MH
	z)	Hz)		z)	Hz)		z)
	23.84	23.78	}	23.62		23.70	23.65
LTE			Cor	nducted Power (dl	Bm)		
Band66	Channel 132572	(1770MHz)	Chai	nnel 132322(1745I	MHz)	Channel 1	32072(1720MHz)
QPSK	23.30			23.44			23.52
LTE			Cor	nducted Power (dl	Bm)		
Band2	Channel 19100	(1900MHz)	Cha	annel18900(1880N	/Hz)	Channel '	18700(1860MHz)
16-QAM	22.80			22.85			22.97
LTE			Cor	nducted Power (dl	Bm)		
Band5	Channel 20600((844MHz)	Char	nnel 20525(836.5M	1Hz)	Channel	20450(829MHz)
16-QAM	22.54			22.25		22.12	
LTE			Cor	nducted Power (di	Bm)		
Band7	Channel 21350	(2560MHz)	Cha	Channel21100(2535MHz) Cha		Channel 2	20850(2510MHz)
16-QAM	22.85			22.87			23.03
LTE			Cor	nducted Power (di	Bm)		
Band12	Channel 23130	(711MHz)	Cha	` '		23060(704MHz)	
16-QAM	22.37	•		21.97 21.94			21.94
LTE			Cor	nducted Power (di	Bm)		
Band13			Cha	annel 23230(782M	Hz)		
16-QAM				22.08			
			Cor	nducted Power (dl	Bm)		
LTE	Channel	Chann	el	Channel	С	hannel	Channel
Band41	41490(2680MH	41055(263	6.5M	40620(2593MH	4018	5(2549.5M	39750(2506MH
16-QAM	z)	Hz)		z)		Hz)	z)
	22.99	23.02		23.19		22.95	22.78
LTE			Cor	nducted Power (di	Bm)		
Band66	Channel 132572	(1770MHz)	Chai	nnel 132322(1745l	MHz)	z) Channel 132072(1720MHz)	
16-QAM	22.86			23.07			23.15

LTE	Conducted Power (dBm)					
Band2	Channel 19100(1900MHz)	Channel18900(1880MHz)	Channel 18700(1860MHz)			
64-QAM	21.40	21.43	21.44			
LTE		Conducted Power (dBm)				
Band5	Channel 20600(844MHz)	Channel 20525(836.5MHz)	Channel20450(829MHz)			
64-QAM	21.46	21.46	21.45			
LTE		Conducted Power (dBm)				
Band7	Channel 21350(2560MHz)	Channel21100(2535MHz)	Channel 20850(2510MHz)			
64-QAM	21.12	21.09	20.82			
LTE	Conducted Power (dBm)					
Band12	Channel 23130(711MHz)	Channel 23095(707.5MHz)	Channel23060(704MHz)			
64-QAM	21.11	21.16	21.14			





LTE		Conducted Power (dBm)						
Band13	Channel 23230(782MHz)							
64-QAM				21.46				
			Cor	nducted Power (di	Bm)			
LTE	Channel	Channe	el	Channel	С	hannel	Channel	
Band41	41490(2680MH	41055(263	6.5M	40620(2593MH	4018	5(2549.5M	39750(2506MH	
64-QAM	z)	Hz)		z) Hz) z)				
	21.76	21.76 21.33 21.08 21.07 2		20.56				
LTE			Cor	nducted Power (di	Bm)			
Band66	Channel 132572	(1770MHz)	Cha	nnel 132322(1745I	MHz)	Channel 1	32072(1720MHz)	
64-QAM	21.23			21.38			21.66	
2.4GHz			Co	onducted Power (dB	m)			
802.11b	Channel 11 (24	462MHz)	C	hannel 6 (2437MH	lz)	Channe	el 1 (2412MHz)	
1M	19.16 19.23 19.47				19.47			
5GHz	Conducted Power (dBm)							
802.11a	Channel 165 (5825MHz)							
18M				17.37				



5 Reference Documents

5.1 Reference Documents for testing

The following document listed in this section is referred for testing.

	<u> </u>	
Reference	Title	Version
ANSI C63.19-2011	American National Standard for Methods of Measurement of	2011
	Compatibility between Wireless Communication Devices and	Edition
	Hearing Aids	
FCC 47 CFR §20.19	Hearing Aid Compatible Mobile Headsets	2015
		Edition
KDB 285076 D01	Equipment Authorization Guidance for Hearing Aid Compatibility	v05



6 OPERATIONAL CONDITIONS DURING TEST

6.1 HAC MEASUREMENT SET-UP

These measurements are performed using the DASY5 NEO automated dosimetric assessment system. It is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland. It consists of high precision robotics system (Stäubli), robot controller, Intel Core2 computer, near-field probe, probe alignment sensor. The robot is a six-axis industrial robot performing precise movements. A cell controller system contains the power supply, robot controller, teach pendant (Joystick),and remote control, is used to drive the robot motors. The PC consists of the HP Intel Core21.86 GHz computer with Windows XP system and HAC Measurement Software DASY5 NEO, A/D interface card, monitor, mouse, and keyboard. The Stäubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE)circuit performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

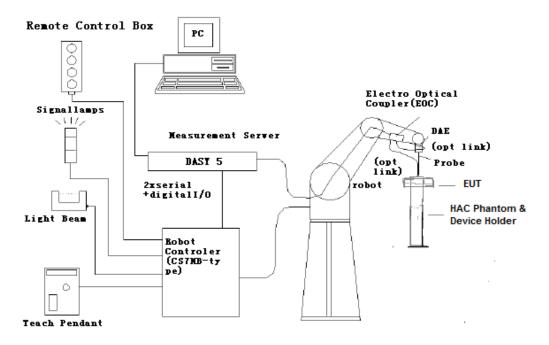


Fig. 1 HAC Test Measurement Set-up

The DAE4 consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.



6.2 Probe Specification

E-Field Probe Description

Construction One dipole parallel, two dipoles normal to probe axis

Built-in shielding against static charges

PEEK enclosure material

Calibration In air from 100 MHz to 3.0 GHz (absolute accuracy ±6.0%,

k=2)

Frequency 40 MHz to > 6 GHz (can be extended to < 20 MHz)

Linearity: ± 0.2 dB (100 MHz to 3 GHz)

Directivity $\pm 0.2 \text{ dB}$ in air (rotation around probe axis)

± 0.4 dB in air (rotation normal to probe axis)

Dynamic Range 2 V/m to > 1000 V/m; Linearity: ± 0.2 dB

Dimensions Overall length: 330 mm (Tip: 16 mm)

Tip diameter: 8 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 2.5 mm

Application General near-field measurements up to 6 GHz

Field component measurements

Fast automatic scanning in phantoms



[ER3DV6]



6.3Test Arch Phantom & Phone Positioner

The Test Arch phantom should be positioned horizontally on a stable surface. Reference markings on the Phantom allow the complete setup of all predefined phantom positions and measurement grids by manually teaching three points in the robot. It enables easy and well defined positioning of the phone and validation dipoles as well as simple teaching of the robot (Dimensions: $370 \times 370 \times 370 \text{ mm}$).

The Phone Positioner supports accurate and reliable positioning of any phone with effect on near field $<\pm 0.5$ dB.

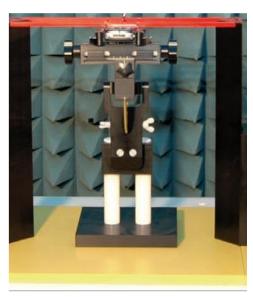


Fig. 2 HAC Phantom & Device Holder

6.4Robotic System Specifications

Specifications

Positioner: Stäubli Unimation Corp. Robot Model: RX160L

Repeatability: ±0.02 mm

No. of Axis: 6

Data Acquisition Electronic (DAE) System

Cell Controller

Processor: Intel Core2 Clock Speed: 1.86GHz

Operating System: Windows XP

Data Converter

Features: Signal Amplifier, multiplexer, A/D converter, and control logic

Software: DASY5 software

Connecting Lines: Optical downlink for data and status info.

Optical uplink for commands and clock



7 EUT ARRANGEMENT

7.1 WD RF Emission Measurements Reference and Plane

Figure 4 illustrates the references and reference plane that shall be used in the WD emissions measurement.

- The grid is 5 cm by 5 cm area that is divided into 9 evenly sized blocks or sub-grids.
- The grid is centered on the audio frequency output transducer of the WD (speaker or T-coil).
- The grid is located by reference to a reference plane. This reference plane is the planar area that contains the highest point in the area of the WD that normally rests against the user's ear
- •The measurement plane is located parallel to the reference plane and 15 mm from it, out from the phone. The grid is located in the measurement plane.

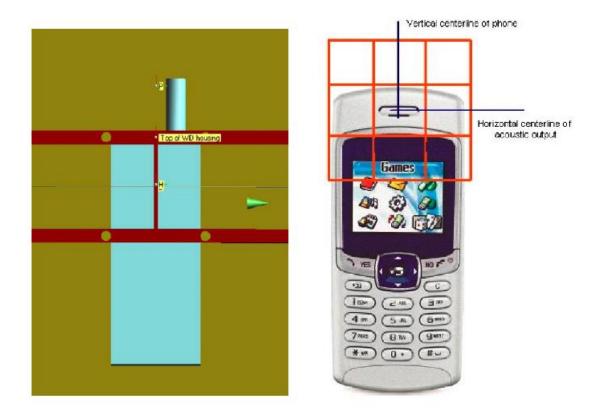


Fig. 3 WD reference and plane for RF emission measurements



8 SYSTEM VALIDATION

8.1 Validation Procedure

Place a dipole antenna meeting the requirements given in ANSI C63.19 in the position normally occupied by the WD. The dipole antenna serves as a known source for an electrical output. Position the E-field probes so that:

- •The probes and their cables are parallel to the coaxial feed of the dipole antenna
- •The probe cables and the coaxial feed of the dipole antenna approach the measurement area from opposite directions
- The center point of the probe element(s) are 15 mm from the closest surface of the dipole elements.

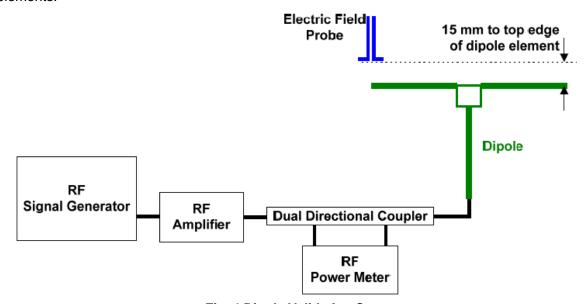


Fig. 4 Dipole Validation Setup

8.2 Validation Result

	E-Field Scan						
Mode	Frequency (MHz)	Input Power (mW)	Measured ¹ Value(dBV/m)	Target ² Value(dBV/m)	Deviation ³ (%)	Limit ⁴ (%)	
CW	835	100	40.61	40.67	-0.69	±25	
CW	1880	100	39.32	39.24	0.93	±25	
CW	2600	100	38.89	38.74	-0.57	±25	

Notes:

- 1. Please refer to the attachment for detailed measurement data and plot.
- 2. Target value is provided by SPEAD in the calibration certificate of specific dipoles.
- 3. Deviation (%) = 100 * (Measured value minus Target value) divided by Target value.
- 4. ANSI C63.19 requires values within \pm 25% are acceptable, of which 12% is deviation and 13% is measurement uncertainty. Values independently validated for the dipole actually used in the measurements should be used, when available.



9 Evaluation of MIF

9.1 Introduction

The MIF (Modulation Interference Factor) is used to classify E-field emission to determine Hearing Aid Compatibility (HAC). It scales the power-averaged signal to the RF audio interference level and is characteristic to a modulation scheme. The HAC standard preferred "indirect" measurement method is based on average field measurement with separate scaling by the MIF. With an Audio Interference Analyzer (AIA) designed by SPEAG specifically for the MIF measurement, these values have been verified by practical measurements on an RF signal modulated with each of the waveforms. The resulting deviations from the simulated values are within the requirements of the HAC standard.

The AIA (Audio Interference Analyzer) is an USB powered electronic sensor to evaluate signals in the frequency range 698MHz - 6 GHz. It contains RMS detector and audio frequency circuits for sampling of the RF envelope.

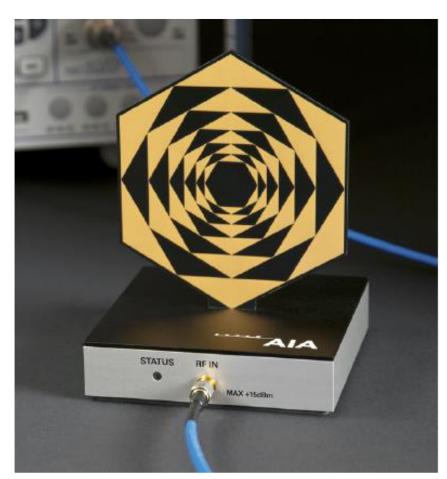


Fig. 5 AIA Front View



9.2 MIF measurement with the AIA

The MIF is measured with the AIA as follows:

- 1. Connect the AIA via USB to the DASY5 PC and verify the configuration settings.
- 2. Couple the RF signal to be evaluated to an AIA via cable or antenna.
- 3. Generate a MIF measurement job for the unknown signal and select the measurement port and timing settings.
- 4. Document the results via the post processor in a report.

9.3 Test equipment for the MIF measurement

No.	Name	Туре	Serial Number	Manufacturer
01	Signal Generator	E4438C	MY49071430	Agilent
02	AIA	SE UMS 170 CB	1029	SPEAG
03	BTS	E5515C	MY50263375	Agilent

9.4 Test signal validation

The signal generator (E4438C) is used to generate a 1GHz signal with different modulation in the below table based on the ANSI C63.19-2011. The measured MIF with AIA are compared with the target values given in ANSI C63.19-2011 table D.3, D.4 and D5.

Pulse modulation	Target MIF	Measured MIF	Deviation
0.5ms pulse, 1000Hz repetition rate	-0.9 dB	-0.9 dB	0 dB
1ms pulse, 100Hz repetition rate	+3.9 dB	+3.7 dB	0.2 dB
0.1ms pulse, 100Hz repetition rate	+10.1 dB	+10.0 dB	0.1 dB
10ms pulse, 10Hz repetition rate	+1.6 dB	+1.7 dB	0.1 dB
Sine-wave modulation	Target MIF	Measured MIF	Deviation
1 kHz, 80% AM	-1.2 dB	-1.3 dB	0.1 dB
1 kHz, 10% AM	-9.1 dB	-9.0 dB	0.1 dB
1 kHz, 1% AM	-19.1 dB	-18.9 dB	0.2 dB
100 Hz, 10% AM	-16.1 dB	-16.0 dB	0.1 dB
10 kHz, 10% AM	-21.5 dB	-21.6 dB	0.1 dB
Transmission protocol	Target MIF	Measured MIF	Deviation
GSM; full-rate version 2; speech codec/handset low	+3.5 dB	+3.47 dB	0.03 dB
WCDMA; speech; speech codec low; AMR 12.2 kb/s	-20.0 dB	-19.8 dB	0.2 dB
CDMA; speech; SO3; RC3; full frame rate; 8kEVRC	-19.0 dB	-19.1 dB	0.1 dB
CDMA; speech; SO3; RC1; 1/8 th frame rate; 8kEVRC	+3.3 dB	+3.44 dB	0.14 dB



9.5 DUT MIF results

Typical MIF levels in ANSI C63.19-2011					
Transmission protocol	Modulation interference factor				
GSM; full-rate version 2; speech codec/handset low	+3.5 dB				
WCDMA; speech; speech codec low; AMR 12.2 kb/s	-20.0 dB				
LTE-FDD (SC-FDMA, 1RB, 20MHz, QPSK)	-15.63 dB				
LTE-FDD (SC-FDMA, 1RB, 20MHz, 16QAM)	-9.76 dB				
LTE-FDD (SC-FDMA, 1RB, 20MHz, 64QAM)	-9.93 dB				
LTE-TDD (SC-FDMA, 1RB, 20MHz, QPSK)	-1.62 dB				
LTE-TDD (SC-FDMA, 1RB, 20MHz, 16QAM)	-1.44 dB				
LTE-TDD (SC-FDMA, 1RB, 20MHz, 64QAM)	-1.54 dB				

	Measured MIF levels					
Band	Channel	Modulation interference factor (dB)				
	251	3.42				
GSM 850	190	3.51				
	128	3.52				
	810	3.51				
GSM 1900	661	3.53				
	512	3.50				
	4458	-23.87				
WCDMA 850	4407	-22.66				
	4357	-24.8				
	1738	-24.26				
WCDMA 1700	1637	-24.18				
	1537	-22.28				
	9938	-24.35				
WCDMA 1900	9800	-24.42				
	9662	-23.07				
1.TE D 10	19100	-14.39				
LTE Band2 QPSK	18900	-14.51				
Qi Oit	18700	-13.83				
LTE D IE	20600	-14.38				
LTE Band5 QPSK	20525	-14.47				
Qi Oit	20450	-14.73				
1.TE D. 17	21350	-14.56				
LTE Band7 QPSK	21100	-14.15				
QI OIX	20850	-14.26				
LTE D. MO	23130	-14.68				
LTE Band12 QPSK	23095	-14.66				
Q. OIX	23060	-15.12				



LTE Band13 QPSK	23230	-14.79
LIE DAHUIS YPSK	132572	-14.79 -14.64
LTE Band66		
QPSK -	132322	-14.25
	132072	-14.32
_	41490	-1.79
LTE Band41	41055	-1.82
QPSK	40620	-1.74
	40185	-1.74
	39750	-1.69
LTE Band2	19100	-9.78
16QAM	18900	-10.24
	18700	-10.93
LTE Band5	20600	-9.9
16QAM	20525	-10.96
·	20450	-9.41
LTC Dand7	21350	-10.62
LTE Band7 16QAM	21100	-10.08
. • • •	20850	-10.54
LTE D 140	23130	-11.65
LTE Band12 16QAM	23095	-10.74
100/11/1	23060	-10.55
LTE Band13 16QAM	23230	-9.49
	132572	-10.49
LTE Band66 16QAM	132322	-10.31
TOQAW	132072	-9.58
	41490	-1.85
	41055	-1.72
LTE Band41 16QAM	40620	-1.7
IOQAW	40185	-1.55
	39750	-1.74
	19100	-10.73
LTE Band2	18900	-10.33
64QAM	18700	-9.59
	20600	-10.16
LTE Band5	20525	-9.52
64QAM	20450	-10.97
	21350	-10.52
LTE Band7	21100	-10.45
64QAM	20850	-9.95
	23130	-10.74
LTE Band12	23095	-10.74
64QAM	23060	-11.51
LTE Band13 64QAM	23230	-11.06
LIL Danu 13 04QAM	23230	-11.00



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1.TE B 100	132572	-10.38
LTE Band66 64QAM	132322	-10.34
OTQ/ (IVI	132072	-9.71
	41490	-1.85
1.75.5	41055	-1.94
LTE Band41 64QAM	40620	-1.63
OTQAM	40185	-1.61
	39750	-1.76
2.4GHz	11	-8.76
802.11b	6	-7.68
5.5M	1	-8.93
5GHz		
802.11a	165	-9.04
18M		



10 Evaluation for low-power exemption

10.1 Product testing threshold

There are two methods for exempting an RF air interface technology from testing. The first method requires evaluation of the MIF for the worst-case operating mode. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is \leq 17 dBm for any of its operating modes. The second method does not require determination of the MIF. The RF emissions testing exemption shall be applied to an RF air interface technology in a device whose peak antenna input power, averaged over intervals \leq 50 $\,\mu$ s20, is \leq 23 dBm. An RF air interface technology that is exempted from testing by either method shall be rated as M4.

The first method is used to be exempt from testing for the RF air interface technology in this report.

10.2 Conducted power

Band	Average power (dBm)	MIF (dB)	Sum (dBm)
GSM 850	32.41	3.52	35.93
GSM 1900	29.26	3.53	32.79
WCDMA 850	23.52	-22.66	0.86
WCDMA 1700	23.86	-22.28	1.58
WCDMA 1900	23.75	-23.07	0.68
LTE B2	23.45	-9.29	14.16
LTE B5	23.15	-9.41	13.74
LTE B7	23.53	-9.95	13.58
LTE B12	23.12	-10.54	12.58
LTE B13	23.02	-9.49	13.53
LTE B66	23.84	-9.58	14.26
LTE B41	23.52	-1.55	21.97
WiFi-2.4G	19.47	-7.68	11.79
WiFi-5G	17.37	-9.04	8.33

10.3 Conclusion

According to the above table, the sums of average power and MIF for UMTS, WiFi and LTE bands except B41 are less than 17dBm. So it is only measured for GSM bands and LTE B41. The others are exempt from testing and rated as M4.